



MIT.9889

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

**APPLICANT:** Lee et al. **GROUP:** 2815  
**SERIAL NO:** 10/603,712 **EXAMINER:** A.R. Wilson  
**FILED:** June 25, 2003  
**FOR:** A METHOD FOR IMPROVING HOLE MOBILITY  
ENHANCEMENT IN STRAINED SILICON P-TYPE  
MOSFET

Mail Stop Amendment  
Commissioner of Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**RESPONSE**

In response to the Office Action mailed February 22, 2004, please amend the  
above-identified application as follows: